100µA

1.0MHz

45pA

5µs

20fA



LMV601/LMV602/LMV604

1 MHz, Low Power General Purpose, 2.7V Operational Amplifiers

General Description

The LMV601/LMV602/LMV604 are single, dual, and quad low voltage, low power Operational Amplifiers. They are designed specifically for low voltage general purpose applications. Other important product characteristics are low input bias current, rail-to-rail output, and wide temperature range. The LMV601/LMV602/LMV604 have 29nV Voltage Noise at 10KHz, 1MHz GBW, 1.0V/ μ s Slew Rate, 0.25mV Vos. The LMV601/2/4 operates from a single supply voltage as low as 2.7V, while drawing 100uA (typ) quiescent current. In shutdown mode the current can be reduced to 45pA.

The industrial-plus temperature range of -40° C to 125° C allows the LMV601/LMV602/LMV604 to accommodate a broad range of extended environment applications.

The LMV601 offers a shutdown pin that can be used to disable the device. Once in shutdown mode, the supply current is reduced to 45pA (typical).

The LMV601 is offered in the tiny 6-Pin SC70 package, the LMV602 in space saving 8-Pin MSOP and SOIC, and the LMV604 in 14-Pin TSSOP and SOIC. These small package amplifiers offer an ideal solution for applications requiring minimum PCB footprint. Applications with area constrained PC board requirements include portable and battery operated electronics.

Features

(Typical 2.7V supply values; unless otherwise noted)

- Guaranteed 2.7V and 5V specifications
- Supply current (per amplifier)
- Gain bandwidth product
- Shutdown Current (LMV601)
- Turn-on time from shutdown (LMV601)Input bias current

Applications

- Cordless/cellular phones
- Laptops
- PDAs
- PCMCIA/Audio
- Portable/battery-powered electronic equipment
- Supply current monitoring
- Battery monitoring
- Buffer
- Filter
- Driver

Sample and Hold Circuit



Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.

ESD Tolerance (<i>Note 2</i>)	
Machine Model	200V
Human Body Model	2000V
Differential Input Voltage	± Supply Voltage
Supply Voltage (V + -V -)	6.0V
Output Short Circuit to V +	(<i>Note 3</i>)
Output Short Circuit to V -	(<i>Note 4</i>)
Storage Temperature Range	–65°C to 150°C
Junction Temperature (Note 5)	150°C
Mounting Temperature	

Infrared or Convection Reflow	
(20 sec.)	235°C
Wave Soldering Lead Temp.	
(10 sec.)	260°C

Operating Ratings (Note 1)

Supply Voltage	2.7V to 5.5V
Temperature Range	–40°C to 125°C
Thermal Resistance (θ_{JA})	
6-Pin SC70	414°C/W
8-Pin SOIC	190°C/W
8-Pin MSOP	235°C/W
14-Pin TSSOP	155°C/W
14-Pin SOIC	145°C/W

2.7V DC Electrical Characteristics (Note 10)

Unless otherwise specified, all limits guaranteed for $T_J = 25^{\circ}C$, $V^+ = 2.7V$, $V^- = 0V$, $V_{CM} = V^+/2$, $V_O = V^+/2$ and $R_L > 1M\Omega$. Boldface limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min (<i>Note 7</i>)	Typ (<i>Note 6</i>)	Max (<i>Note 7</i>)	Units
V _{OS}	Input Offset Voltage	LMV601		0.25	4	mV
		LMV602/LMV604		0.55	5	
TCV _{OS}	Input Offset Voltage Average Drift			1.7		μV/°C
I _B	Input Bias Current			0.02		pА
I _{OS}	Input Offset Current			6.6		fA
I _s	Supply Current	Per Amplifier		100	170	μA
		Shutdown Mode, V _{SD} = 0V (LMV601)		45pA	1µA	
CMRR Common Mode Rejection F	Common Mode Rejection Ratio	$0V \le V_{CM} \le 1.7V$		80		dB
		$0V \le V_{CM} \le 1.6V$				
PSRR	Power Supply Rejection Ratio	2.7V ≤ V+ ≤ 5V		82		dB
V _{CM}	Input Common Mode Voltage	For CMRR ≥ 50dB	0	-0.2 to 1.9 (Range)	1.7	V
A _V	Large Signal Voltage Gain	$R_L = 10k\Omega$ to 1.35V		113		dB
Vo	Output Swing	$R_1 = 10 k\Omega$ to 1.35V		5.0	30	
		-	30	5.3		mV
I _O Out	Output Short Circuit Current	Sourcing LMV601/LMV602		32		
		Sourcing LMV604		24		mA
		Sinking		24		
t _{on}	Turn-on Time from Shutdown	(LMV601)		5		μs
V _{SD}	Shutdown Pin Voltage Range	ON Mode (LMV601)		1.7 to 2.7	2.4 to 2.7	V
		Shutdown Mode (LMV601)		0 to 1	0 to 0.8	v

LMV601/LMV602/LMV604

2.7V AC Electrical Characteristics (Note 10)

Unless otherwise specified, all limits guaranteed for $T_J = 25^{\circ}C$, $V^+ = 2.7V$, $V^- = 0V$, $V_{CM} = V^+/2$, $V_O = V^+/2$ and $R_L > 1M\Omega$. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min (<i>Note 7</i>)	Typ (<i>Note 6</i>)	Max (<i>Note 7</i>)	Units
SR	Slew Rate	R _L = 10kΩ, (<i>Note 9</i>)		1.0		V/µs
GBW	Gain Bandwidth Product	$R_{L} = 100 k\Omega, C_{L} = 200 pF$		1.0		MHz
Φ _m	Phase Margin	$R_L = 100 k\Omega$		72		deg
G _m	Gain Margin	$R_L = 100 k\Omega$		20		dB
e _n	Input-Referred Voltage Noise	f = 1kHz		40		nV/√Hz
i _n	Input-Referred Current Noise	f = 1kHz		0.001		pA/√Hz
THD	Total Harmonic Distortion	$f = 1 kHz, A_V = +1$		0.017		%
		$R_L = 600\Omega, V_{IN} = 1V_{PP}$				

5V DC Electrical Characteristics (Note 10)

Unless otherwise specified, all limits guaranteed for $T_J = 25^{\circ}C$, $V^+ = 5V$, $V^- = 0V$, $V_{CM} = V^+/2$, $V_O = V^+/2$ and $R_L > 1M\Omega$. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
			(<i>Note 7</i>)	(<i>Note 6</i>)	(Note 7)	
V _{os}	Input Offset Voltage	LMV601		0.25	4	
		LMV602/LMV604		0.70	5	mV
TCV _{OS}	Input Offset Voltage Average Drift			1.9		µV/°C
I _B	Input Bias Current			0.02		pА
I _{os}	Input Offset Current			6.6		fA
I _s	Supply Current	Per Amplifier		107	200	μA
		Shutdown Mode, V _{SD} = 0V (LMV601)		0.033	1	μA
CMRR	Common Mode Rejection Ratio	$0V \le V_{CM} \le 4.0V$ $0V \le V_{CM} \le 3.9V$		86		dB
PSRR	Power Supply Rejection Ratio	2.7V ≤ V+ ≤ 5V		82		dB
V _{CM}	Input Common Mode Voltage	For CMRR ≥ 50dB	0	-0.2 to 4.2 (Range)	4	V
A _V	Large Signal Voltage Gain (<i>Note</i> 8)	$R_L = 10k\Omega$ to 2.5V		116		dB
Vo	Output Swing	$R_L = 10k\Omega$ to 2.5V		7	30	m\/
			30	7		mV
I _o	Output Short Circuit Current	Sourcing		113		mA
-		Sinking		75		ШA
t _{on}	Turn-on Time from Shutdown	(LMV601)		5		μs
V _{SD}	Shutdown Pin Voltage Range	ON Mode (LMV601)		3.1 to 5	4.5 to 5.0	V
		Shutdown Mode (LMV601)		0 to 1	0 to 0.8	v

5V AC Electrical Characteristics (Note 10)

Unless otherwise specified, all limits guaranteed for $T_J = 25^{\circ}C$, $V^+ = 5V$, $V^- = 0V$, $V_{CM} = V^+/2$, $V_O = V^+/2$ and $R_L > 1M\Omega$. **Bold-face** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min (<i>Note 7</i>)	Typ (<i>Note 6</i>)	Max (<i>Note 7</i>)	Units
SR	Slew Rate	R _L = 10kΩ, (<i>Note 9</i>)		1.0		V/µs
GBW	Gain-Bandwidth Product	$R_L = 10k\Omega, C_L = 200pF$		1.0		MHz

LMV601/LMV602/LMV604

Symbol	Parameter	Conditions	Min (<i>Note 7</i>)	Typ (<i>Note 6</i>)	Max (<i>Note 7</i>)	Units
Φ _m	Phase Margin	$R_L = 100 k\Omega$		70		deg
G _m	Gain Margin	$R_L = 100 k\Omega$		20		dB
e _n	Input-Referred Voltage Noise	f = 1kHz		39		nV/√Hz
i _n	Input-Referred Current Noise	f = 1kHz		0.001		pA/√Hz
THD	Total Harmonic Distortion	$f = 1 kHz, A_V = +1$		0.012		%
		$R_{L} = 600\Omega, V_{IN} = 1V_{PP}$				

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics. Note 2: Human Body Model, applicable std. MIL-STD-883, Method 3015.7. Machine Model, applicable std. JESD22-A115-A (ESD MM std. of JEDEC) Field-Induced Charge-Device Model, applicable std. JESD22-C101-C (ESD FICDM std. of JEDEC).

Note 3: Shorting output to V+ will adversely affect reliability.

Note 4: Shorting output to V- will adversely affect reliability.

Note 5: The maximum power dissipation is a function of $T_{J(MAX)}$, θ_{JA} . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(MAX)} - T_A)/\theta_{JA}$. All numbers apply for packages soldered directly onto a PC Board.

Note 6: Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material. Note 7: All limits are guaranteed by testing or statistical analysis.

Note 8: R_L is connected to mid-supply. The output voltage is GND + 0.2V \leq V₀ \leq V⁺ -0.2V

Note 9: Connected as voltage follower with 2V_{PP} step input. Number specified is the slower of the positive and negative slew rates.

Note 10: Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that T_J = T_A. No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self heating where T_J > T_A.

Connection Diagrams



Ordering Information

Package	Part Number	Package Marking	Transport Media	NSC Drawing	
6-Pin SC70	LMV601MG	A11A	1k Units Tape and Reel		
6-PIN 5070	LMV601MGX	AUA	3k Units Tape and Reel	MAA06A	
8-Pin MSOP	LMV602MM	AC9A	1k Units Tape and Reel	MUA08A	
0-FIII MISOF	LMV602MMX	AC9A	3.5k Units Tape and Reel	IVIUAU8A	
8-Pin SOIC	LMV602MA	LMV602MA	95 Units/Rail	MORA	
0-PIN 5010	LMV602MAX		2.5k Units Tape and Reel	M08A	
14-Pin TSSOP	LMV604MT	LMV604MT	Rails	MTC14	
14-FIII 1330P	LMV604MTX		2.5k Units Tape and Reel	- MTC14	
14-Pin SOIC	LMV604MA	LMV604MA	55 Units/Rail	N414A	
14-2111 2010	LMV604MAX		2.5k Units Tape and Reel	M14A	



Typical Performance Characteristics

LMV601/LMV602/LMV604

Input Current vs. Temperature



30185546

Output Voltage Swing vs. Supply Voltage























30185549

Non-Inverting Large Signal Pulse Response



30185508

Stability vs. Capacitive Load $V_{S} = \pm 2.5V$ $A_{L} = \pm 1$



Non-Inverting Small Signal Pulse Response



30185505

Non-Inverting Small Signal Pulse Response







Non-Inverting Large Signal Pulse Response





Non-Inverting Small Signal Pulse Response

















30185516





Crosstalk Rejection vs. Frequency



Application Section

The LMV601/LMV602/LMV604 family of amplifiers features low voltage, low power, and rail-to-rail output operational amplifiers designed for low voltage portable applications. The family is designed using all CMOS technology. This results in an ultra low input bias current. The LMV601 has a shutdown option, which can be used in portable devices to increase battery life.

A simplified schematic of the LMV601/LMV602/LMV604 family of amplifiers is shown in *Figure 1*. The PMOS input differential pair allows the input to include ground. The output of this differential pair is connected to the Class AB turnaround stage. This Class AB turnaround has a lower quiescent current, compared to regular turnaround stages. This results in lower offset, noise, and power dissipation, while slew rate equals that of a conventional turnaround stage. The output of the Class AB turnaround stage provides gate voltage to the complementary common-source transistors at the output stage. These transistors enable the device to have rail-to-rail output.



FIGURE 1. Simplified Schematic

CLASS AB TURNAROUND STAGE AMPLIFIER

This patented folded cascode stage has a combined class AB amplifier stage, which replaces the conventional folded cascode stage. Therefore, the class AB folded cascode stage runs at a much lower quiescent current compared to conventional folded cascode stages. This results in significantly smaller offset and noise contributions. The reduced offset and noise contributions in turn reduce the offset voltage level and the voltage noise level at the input of the LMV601/LMV602/LMV604. Also the lower quiescent current results in a high open-loop gain for the amplifier. The lower quiescent current does not affect the slew rate of the amplifier nor its ability to handle the total current swing coming from the input stage.

The input voltage noise of the device at low frequencies, below 1kHz, is slightly higher than devices with a BJT input stage; However the PMOS input stage results in a much lower input bias current and the input voltage noise drops at frequencies above 1kHz.

SAMPLE AND HOLD CIRCUIT

The lower input bias current of the LMV601 results in a very high input impedance. The output impedance when the device is in shutdown mode is quite high. These high impedances, along with the ability of the shutdown pin to be derived from a separate power source, make LMV601 a good choice for sample and hold circuits. The sample clock should be connected to the shutdown pin of the amplifier to rapidly turn the device on or off.

Figure 2 shows the schematic of a simple sample and hold circuit. When the sample clock is high the first amplifier is in normal operation mode and the second amplifier acts as a buffer. The capacitor, which appears as a load on the first amplifier, will be charging at this time. The voltage across the capacitor is that of the non-inverting input of the first amplifier since it is connected as a voltage-follower. When the sample clock is low the first amplifier is shut off, bringing the output impedance to a high value. The high impedance of this output, along with the very high impedance on the input of the second amplifier, prevents the capacitor from discharging. There is very little voltage droop while the first amplifier is in shutdown mode. The second amplifier, which is still in normal operation mode and is connected as a voltage follower, also provides the voltage sampled on the capacitor at its output.



30185544

FIGURE 2. Sample and Hold Circuit

SHUTDOWN FEATURE

The LMV601 is capable of being turned off in order to conserve power and increase battery life in portable devices. Once in shutdown mode the supply current is drastically reduced, $1\mu A$ maximum, and the output will be "tri-stated."

The device will be disabled when the shutdown pin voltage is pulled low. The shutdown pin should never be left unconnected. Leaving the pin floating will result in an undefined operation mode and the device may oscillate between shutdown and active modes.

The LMV601 typically turns on 2.8µs after the shutdown voltage is pulled high. The device turns off in less than 400ns after shutdown voltage is pulled low. *Figure 3* and *Figure 4* show the turn-on and turn-off time of the LMV601, respectively. In order to reduce the effect of the capacitance added to the circuit by the scope probe, in the turn-off time circuit a resistive load of 600Ω is added. *Figure 5* and *Figure 6* show the test circuits used to obtain the two plots.











FIGURE 5. Turn-on Time



FIGURE 6. Turn-off Time

LOW INPUT BIAS CURRENT

The LMV601/LMV602/LMV604 Amplifiers have a PMOS input stage. As a result, they will have a much lower input bias current than devices with BJT input stages. This feature makes these devices ideal for sensor circuits. A typical curve of the input bias current of the LMV601 is shown in *Figure 7*.



FIGURE 7. Input Bias Current vs. V_{CM}



Physical Dimensions inches (millimeters) unless otherwise noted SYMM ⊄ ► C 2 ± 0 SYMM ((4X 0.65) 4X 0.65 -PIN 1 INDEX AREA В SYMM ⊄ -9) 1.8 2.4 1.25±0.1 0 75 (6) (6X 0,4) (1.3) 6X 0.15-0.30 ⊕0.1⊗ABS_CS 1.3 LAND PATTERN RECOMMENDATION R0 025 MIN R0.025 A ∩° - 5° TYP 0.1 A 0-0.1 SEATING PLANE-6X 0.40±0.05 0.1-0.20 Typ - (0.515 TYP) DIMENSIONS ARE IN MILLIMETERS

MAA06A (Rev B)

¥

GAGE PLANE

0.2





MUA08A (Rev F)

8-Pin MSOP NS Package Number MUA08A







14-Pin SOIC NS Package Number M14A

Notes

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